NSN 5962-01-390-2011

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:	
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500.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
End Application:	
Cv-3993/sys-2 e/i fscm 21877	
Features Provided:	
Programmed and ultraviolet erasable and electrostatic sensitive	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Complementary-metal oxide-semiconductor logic	
Product Name:	
32k x 8-bit prom	
Voltage Rating And Type Per Characteristic:	
4.5 volts applied and 5.5 volts applied	
Time Rating Per Chacteristic:	
70.00 nanoseconds af output megawatts	
Memory Device Type:	
Prom	
Hybrid Technology Type:	
Monolithic	
Test Data Document:	
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specific	ecification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on cer	tain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-	-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.).	
Terminal Type And Quantity:	
28 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	